

## Technical Data Sheet

### 2.75× 5.25mm Silicon PIN Photodiode

#### PD638B/C1

#### Features

- Fast response time
- High photo sensitivity
- Small junction capacitance

#### Descriptions

PD638B/C1 is a high speed and sensitive PIN photodiode in a flat side view plastic package. The epoxy package itself is an IR filter, spectrally matched to IR emitters.

#### Applications

- High speed photo detector
- Camera
- Optoelectronic switch
- VCRs , Video camera

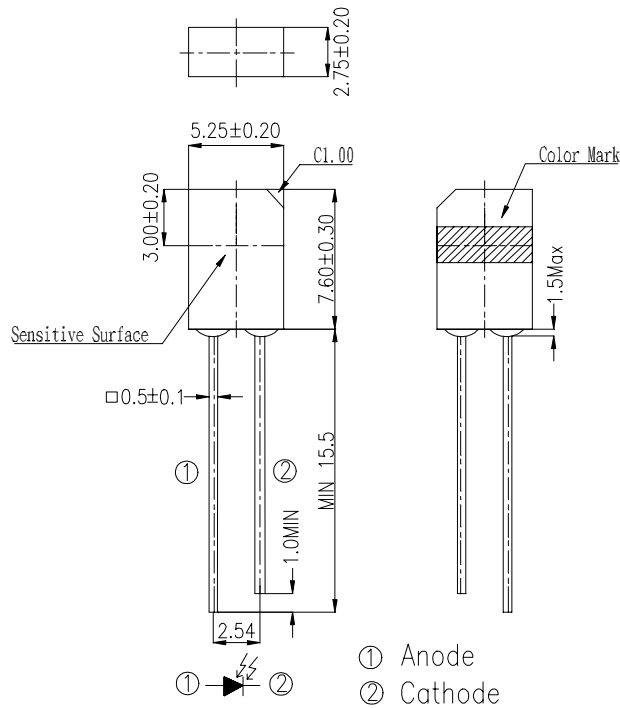


#### Device Selection Guide

LED Part No.	Chip	Lens Color
	Material	
PD	Silicon	Black

Device No:DPD-063-034

**Package Dimensions**



- Notes:** 1. All dimensions are in millimeters  
 2. Tolerances unless dimensions ± 0.1mm

**Absolute Maximum Ratings (Ta=25°C)**

Parameter	Symbol	Rating	Units
Reverse Voltage	V <sub>R</sub>	32	V
Power Dissipation	P <sub>d</sub>	150	mW
Lead Soldering Temperature	T <sub>sol</sub>	260	°C
Operating Temperature	T <sub>opr</sub>	-25 ~ +85	°C
Storage Temperature	T <sub>stg</sub>	-40 ~ +85	°C

**Notes:** \*1: Soldering time ≤ 5 seconds.

**Electro-Optical Characteristics (Ta=25°C)**

Parameter	Symbol	Condition	Min.	Typ.	Max.	Units
Rang of Spectral Bandwidth	$\lambda_{0.5}$	-----	760	---	1200	nm
Wavelength of Peak Sensitivity	$\lambda_p$	-----	---	940	---	nm
Open-Circuit Voltage	$V_{OC}$	Ee=5m W/cm <sup>2</sup> $\lambda_p=940\text{nm}$	---	0.35	---	V
Short- Circuit Current	$I_{SC}$	Ee=1m W/cm <sup>2</sup> $\lambda_p=940\text{nm}$	---	45	---	$\mu\text{A}$
Reverse Light Current	$I_L$	Ee=1m W/cm <sup>2</sup> $\lambda_p=940\text{nm}$ $V_R=5\text{V}$	---	45	---	
Dark Current	$I_d$	Ee=0m W/cm <sup>2</sup> $V_R=10\text{V}$	---	5	30	nA
Reverse Breakdown	$BV_R$	Ee=0m W/cm <sup>2</sup> $I_R=100\ \mu\text{A}$	32	170	---	V
Total Capacitance	$C_t$	Ee=0m W/cm <sup>2</sup> $V_R=3\text{V}$ $f=1\text{MHZ}$	---	25	---	pF
Rise/Fall Time	$t_r/t_f$	$V_R=10\text{V}$ $R_L=1\text{K}\ \Omega$	---	50/50	---	nS

**Typical Electro-Optical Characteristics Curves**

Fig. 1 Power Dissipation vs. Ambient Temperature

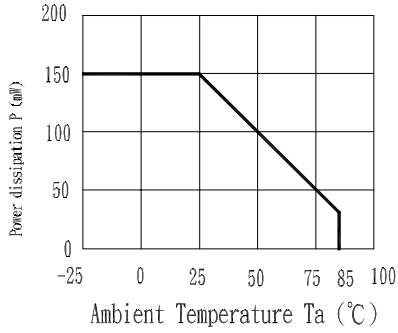


Fig. 2 Spectral Sensitivity

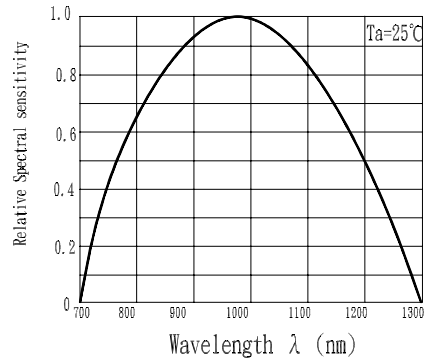


Fig. 3 Dark Current vs. Ambient Temperature

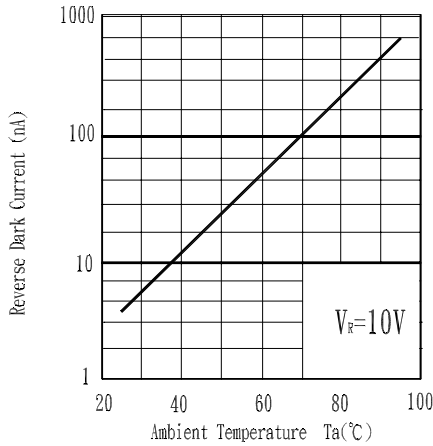


Fig. 4 Reverse Light Current vs.  $E_e$

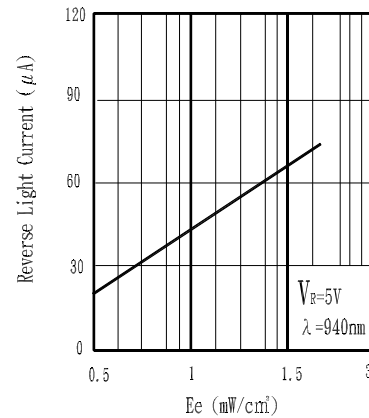


Fig. 5 Terminal Capacitance vs. Reverse Voltage

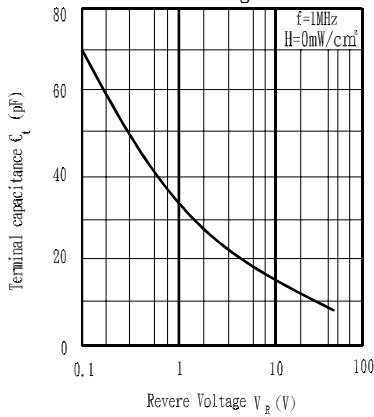
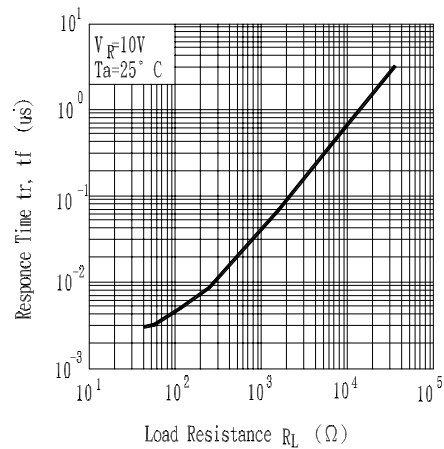


Fig. 6 Responce Time vs. Load Resistance



Device No:DPD-063-034

**Reliability Test Item And Condition**

The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

LTPD : 10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgement Criteria	Ac/Re
1	Solder heat	TEMP. : 260°C ± 5°C	10sec	22pcs	$I_R \geq U \times 2$ $E_e \leq L \times 0.8$ $V_F \geq U \times 1.2$  U : Upper Specification  Limit L : Lower Specification Limit	0/1
2	Temperature Cycle	H : +85°C    30mins ↑ 5mins ↓ L : -55°C    30mins	50Cycle	22pcs		0/1
3	Thermal Shock	H : +100°C    5mins ↑ 10secs ↓ L : -10°C    5mins	50Cycle	22pcs		0/1
4	High Temperature Storage	TEMP. : +100°C	1000hrs	22pcs		0/1
5	Low Temperature Storage	TEMP. : -55°C	1000hrs	22pcs		0/1
6	DC Operating Life	$V_R = 5V$	1000hrs	22pcs		0/1
7	High Temperature/ High Humidity	85°C / 85% R.H	1000hrs	22pcs		0/1

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